## TNPW e3



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RoHS

COMPLIANT

# High Stability Thin Film Flat Chip Resistor $\leq$ 0.05 % (1000 h rated power at 70 °C)



TNPW e3 Precision Thin Film Flat Chip Resistors are the perfect choice for most fields of modern electronics where highest reliability and stability is of major concern. Typical applications include automotive, telecommunication, industrial, medical equipment, precision test and measuring equipment.

#### FEATURES

- Superior moisture resistivity  $\leq$  0.25 % (85 °C; 56 days; 85 % RH)
- · Lead (Pb)-free solder contacts, RoHS compliant
- AEC-Q200 compliant (sizes 0402 to 1206)
- Low temperature coefficient and tight tolerances (± 0.1 %; ± 10 ppm/K)
- Waste gas resistant

#### **APPLICATIONS**

- · Test and measuring equipment
- Telecommunication
- Medical equipment
- Industrial equipment
- Instrumentation
- Automotive

DESCRIPTION	TNPW0402	TNPW0603	TNPW0805	<b>TNPW1206</b>	TNPW1210 <sup>(1)</sup>	TNPW2010	TNPW2512 <sup>(1)</sup>
Metric size	RR 1005M	RR 1608M	RR 2012M	RR 3216M	RR 3225M	RR 5025M	RR 6332M
Resistance range	10 $\Omega$ to 100 k $\Omega$	10 $\Omega$ to 332 k $\Omega$	10 $\Omega$ to 1 $M\Omega$	10 $\Omega$ to 2 M $\Omega$	10 $\Omega$ to 3.01 $M\Omega$	10 $\Omega$ to 4.99 $M\Omega$	10 $\Omega$ to 8.87 $M\Omega$
Resistance tolerance			3	± 1 %; ± 0.5 %;	± 0.1 %		
Temperature coefficent	±	50 ppm/K; ± 25	ppm/K; ± 15 pj	om/K; ± 10 ppn	n/K	± 50 ppm/K	; ± 25 ppm/K
Climatic category (LCT/UCT/days)	55/125/56	55/125/56	55/125/56	55/125/56	55/125/56	55/125/56	55/125/56
Rated dissipation, $P_{70}^{(2)}$	0.063 W	0.1 W	0.125 W	0.25 W	0.33 W	0.4 W	0.5 W
Operating voltage, U <sub>max.</sub> AC/DC	50 V	75 V	150 V	200 V	200 V	300 V	300 V
Maximum permissible film temperature	155 °C	155 °C	155 °C	155 °C	155 °C	155 °C	155 °C
Thermal resistance (3)	870 K/W	550 K/W	440 K/W	220 K/W	170 K/W	140 K/W	110 K/W
Max. resistance change at $P_{70}$ ; $\Delta R/R$	10 $\Omega$ to 100 k $\Omega$	10 $\Omega$ to 332 k $\Omega$	10 $\Omega$ to 1 M $\Omega$	10 $\Omega$ to 2 M $\Omega$	10 $\Omega$ to 3.01 $M\Omega$	10 $\Omega$ to 4.99 M $\Omega$	10 Ω to 8.87 MΩ
1000 h	≤ 0.05 %	≤ 0.05 %	≤ 0.05 %	≤ 0.05 %	≤ 0.05 %	≤ 0.05 %	≤ 0.05 %
8000 h	≤ 0.10 %	≤ 0.10 %	≤ 0.10 %	≤ 0.10 %	≤ 0.10 %	≤ 0.10 %	≤ 0.10 %
225 000 h	≤ 0.30 %	≤ 0.30 %	≤ 0.30 %	$\leq$ 0.30 %	≤ 0.30 %	≤ 0.30 %	≤ 0.30 %
Insulation voltage:							
U <sub>ins</sub> 1 min	75 V	100 V	200 V	300 V	300 V	300 V	300 V
Continuous	75 V	75 V	75 V	75 V	75 V	75 V	75 V
FIT <sub>observed</sub>	$\leq$ 0.1 x 10 <sup>-9</sup> /h	$\leq$ 0.1 x 10 <sup>-9</sup> /h	$\le 0.1 \text{ x } 10^{-9}/h$	≤ 0.1 x 10 <sup>-9</sup> /h	≤ 0.1 x 10 <sup>-9</sup> /h	≤ 0.1 x 10 <sup>-9</sup> /h	≤ 0.1 x 10 <sup>-9</sup> /h
Weight/1000 pieces	0.65 g	2 g	5.5 g	10 g	16 g	28 g	39 g

#### Notes

<sup>(1)</sup> Size not specified in EN 140401-801

(2) Rated voltage  $\sqrt{P \times R}$ . The power dissipation on the resistor generates a temperature rise against the local ambient, depending on the heat flow support of the printed-circuit board (thermal resistance). Using advanced temperature level may require special considerations towards the choice of circuit board and solder material. The rated dissipation applies only if the permitted film temperature is not exceeded.

 $^{(3)}\,$  Measuring conditions in accordance with EN 140401-801  $\,$ 

TNPW 0402 without marking

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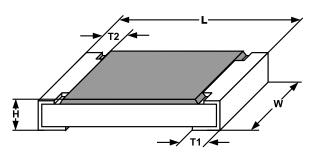
## **TNPW e3**

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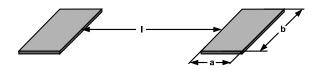
# High Stability Thin Film Flat Chip Resistor $\leq$ 0.05 % (1000 h rated power at 70 °C)



#### DIMENSIONS



S	IZE	DIMENSIONS in millimeters					
INCH	METRIC	L	W	Н	T1	T2	
0402	1005	$1.0 \pm 0.05$	$0.5 \pm 0.05$	$0.35\pm0.05$	0.2 ±	0.10	
0603	1608	$1.6 \pm 0.10$	$0.85 \pm 0.10$	$0.45\pm0.10$	0.3 ±	0.20	
0805	2012	$2.0 \pm 0.15$	1.25 ± 0.15	$0.45\pm0.10$	0.4 ±	0.20	
1206	3216	$3.2 \pm 0.15$	1.6 ± 0.15	$0.55\pm0.10$	0.5 ±	0.25	
1210	3225	$3.2 \pm 0.15$	$2.45 \pm 0.15$	$0.60\pm0.15$	0.5 ±	0.25	
2010	5025	$5.0 \pm 0.15$	$2.5 \pm 0.15$	$0.60\pm0.15$	0.6 ±	0.25	
2512	6332	$6.3 \pm 0.20$	3.1 ± 0.15	$0.60\pm0.15$	0.6 ±	0.25	



	SOLDER PAD DIMENSIONS in millimeters							
S	SIZE REFLOW SOLDERING WAVE SOLDER			RING				
INCH	METRIC	а	b	-	а	b	I	
0402	1005	0.4	0.6	0.5	-	-	-	
0603	1608	0.5	0.9	1.0	0.9	0.9	1.0	
0805	2012	0.7	1.3	1.2	0.9	1.3	1.3	
1206	3216	0.9	1.7	2.0	1.1	1.7	2.3	
1210	3225	0.9	2.5	2.0	1.1	2.5	2.3	
2010	5025	1.0	2.5	3.9	1.2	2.5	3.9	
2512	6332	1.0	3.2	5.2	1.2	3.2	5.2	

ТҮРЕ	TCR	TOLERANCE	RESISTANCE VALUE	E-SERIES	
		±1%	10R to 100K	24 to 96	
	± 50 ppm/K	± 0.5 %	10R to 100K	04 to 100	
TNPW0402		± 0.1 %	47R to 100K		
		±1%	10R to 100K	24 to 96	
1117 100402	± 25 ppm/K	± 0.5 %	10R to 100K		
		± 0.1 %		24 to 192	
	± 15 ppm/K	± 0.1 %	47R to 100K	24 10 192	
	± 10 ppm/K	± 0.1 %			
		±1%	10R to 332K	24 to 96	
	± 50 ppm/K	± 0.5 %	10R to 332K		
TNPW0603		± 0.1 %			
		±1%	10R to 332K	24 to 96	
	± 25 ppm/K	± 0.5 %	10R to 332K		
		± 0.1 %		24 to 192	
	± 15 ppm/K	± 0.1 %	47R to 332K		
	± 10 ppm/K	± 0.1 %			
		±1%	10R to 1M0	24 to 96	
	± 50 ppm/K	± 0.5 %	10R to 1M0	24 to 192	
		± 0.1 %			
TNPW0805		±1%	10R to 1M0	24 to 96	
	± 25 ppm/K	± 0.5 %	10R to 1M0		
		± 0.1 %		24 to 192	
	± 15 ppm/K	± 0.1 %	47R to 1M0		
	± 10 ppm/K	± 0.1 %			
		± 1 %	10R to 2M0	24 to 96	
	± 50 ppm/K	± 0.5 %	10R to 2M0	24 to 192	
		± 0.1 %			
TNPW1206		± 1 %	10R to 2M0	24 to 96	
	± 25 ppm/K	± 0.5 %	10R to 2M0		
	45	± 0.1 %		24 to 192	
	± 15 ppm/K	± 0.1 %	47R to 2M0		
	± 10 ppm/K	± 0.1 %			

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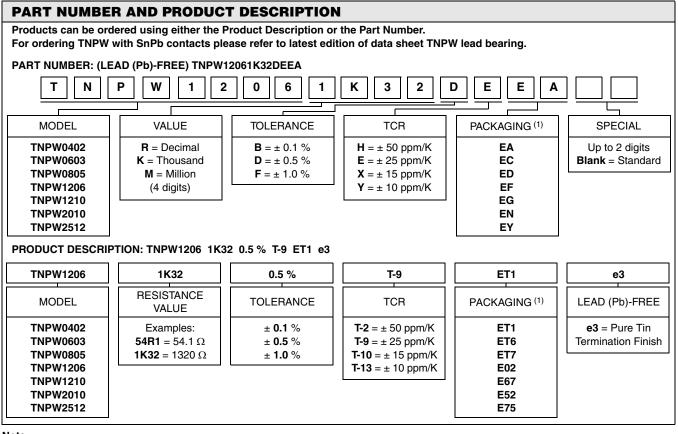
## High Stability Thin Film Flat Chip Resistor $\leq 0.05$ % (1000 h rated power at 70 °C)

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TEMPERATUR	E COEFFICIENT AN	ND RESISTANCE R	ANGE		
TYPE	TCR	TOLERANCE	RESISTANCE VALUE	E-SERIES	
		±1%	10R to 3M01	24 to 96	
	± 50 ppm/K	± 0.5 %	10R to 3M01	04 to 100	
	Γ	± 0.1 %	47R to 2M13	24 to 192	
TNPW1210		±1%	10R to 3M01	24 to 96	
	± 25 ppm/K	± 0.5 %	10R to 3M01		
		± 0.1 %		24 to 192	
	± 15 ppm/K	± 0.1 %	47R to 2M13	24 10 192	
	± 10 ppm/K	± 0.1 %			
		±1%	10R to 4M99	24 to 96	
	± 50 ppm/K	± 0.5 %	10R to 4M99	24 to 192	
TNPW2010		± 0.1 %	47R to 1M0	24 10 192	
		±1%	10R to 4M99	24 to 96	
	± 25 ppm/K	± 0.5 %	10R to 4M99	04 to 100	
	Γ	± 0.1 %	47R to 1M0	24 to 192	
		±1%	10R to 8M87	24 to 96	
	± 50 ppm/K	± 0.5 %	10R to 8M87	04 to 100	
TUDWOSTO	Γ	± 0.1 %	47R to 1M0	24 to 192	
TNPW2512		±1%	10R to 8M87	24 to 96	
	± 25 ppm/K	± 0.5 %	10R to 8M87	24 to 192	
	Γ	± 0.1 %	47R to 1M0	24 (0 192	



#### Note

<sup>(1)</sup> Please refer to PACKAGING table

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PACKAGIN	PACKAGING								
MODEL	TAPE WIDTH [mm]	PITCH [mm]	REEL DIAMETER [mm/inch]	PIECES PER REEL	PACKAGING CODE FOR PRODUCT DESCRIPTION	PACKAGING CODE FOR PART NUMBER	TYPE OF CARRIER TAPE		
TNPW0402	8	2	180/7	10 000	ET7	ED	Paper		
TNPW0603 TNPW0805 TNPW1206 TNPW1210	8	4	180/7	1000	E52 <sup>(1)</sup>	EN <sup>(1)</sup>	Paper		
TNPW0603 TNPW0805 TNPW1206 TNPW1210	8	4	180/7	5000	ET1	EA	Paper		
TNPW0603 TNPW0805 TNPW1206 TNPW1210	8	4	330/13	20 000	ET6	EC	Paper		
TNPW2010	12	4	180/7	1000	E75	EY	Blister		
	12	4	100/7	4000	E02	EF	Blister		
TNPW2512	12	4	180/7	1000	E75	EY	Blister		
1115 102312	12	4	100/7	2000	E67	EG	Blister		

Note

<sup>(1)</sup> E52/EN only for precision resistors with tolerance  $\pm$  0.1 % and temperature coefficient  $\leq \pm$  25 ppm/K

#### DESCRIPTION

Production is strictly controlled and follows an extensive set of instructions established for reproducibility. A homogeneous film of metal alloy is deposited on a high grade Al<sub>2</sub>O<sub>3</sub> ceramic substrate and conditioned to achieve the desired temperature coefficient. Specially designed inner contacts are deposited on both sides. A special laser is used to achieve the target value by smoothly fine trimming the resistive layer without damaging the ceramics. A further conditioning is applied in order to stabilize the trimming result. The resistor elements are covered by a protective coating designed for electrical, mechanical and climatic protection. The terminations receive a final pure tin on nickel plating. The result of the determined production is verified by an extensive testing procedure on 100 % of the individual chip resistors. This includes pulse load screening for the elimination of products with a potential risk of early life failures according to EN 140401-801, 2.1.2.2. Only accepted products are laid directly into the tape in accordance with EN 60286-3.

#### ASSEMBLY

The resistors are suitable for processing on automatic SMD assembly systems. They are suitable for automatic soldering using wave, reflow or vapour phase as shown in **IEC 61760-1**. Excellent solderability is proven, even after extended storage in excess of 10 years. The encapsulation is resistant to all cleaning solvents commonly used in the electronics industry, including alcohols, esters and aqueous solutions. The suitability of conformal coatings, if applied, shall be qualified by appropriate means to ensure the long-term stability of the whole system. The resistors are RoHS compliant, the puretin plating provides compatibility with lead (Pb)-free and lead-containing soldering processes. The immunity of the plating against tin whisker growth has been proven under extensive testing.

All products comply with the **GADSL**<sup>(2)</sup> and the **CEFIC-EECA-EICTA**<sup>(3)</sup> list of legal restrictions on hazardous substances. This includes full compliance with the following directives:

- 2000/53/EC End of Vehicle life Directive (ELV) and Annex II (ELV II)
- 2002/95/EC Restriction of the use of Hazardous Substances Directive (RoHS)
- 2002/96/EC Waste Electrical and Electronic Equipment Directive (WEEE)

Solderability is specified for 2 years after production or re-qualification. The permitted storage time is 20 years.

#### Notes

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<sup>(2)</sup> Global Automotive Declarable Substance List, see <u>www.gadsl.org</u>

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<sup>&</sup>lt;sup>(3)</sup> CEFIC (European Chemical Industry Council), EECA (European Electronic Component Manufacturers Association), EICTA (European trade organisation representing the information and communications technology and consumer electronics), see <u>www.eicta.org</u>  $\rightarrow$  issue  $\rightarrow$  environment policy  $\rightarrow$  chemicals  $\rightarrow$  chemicals for electronics

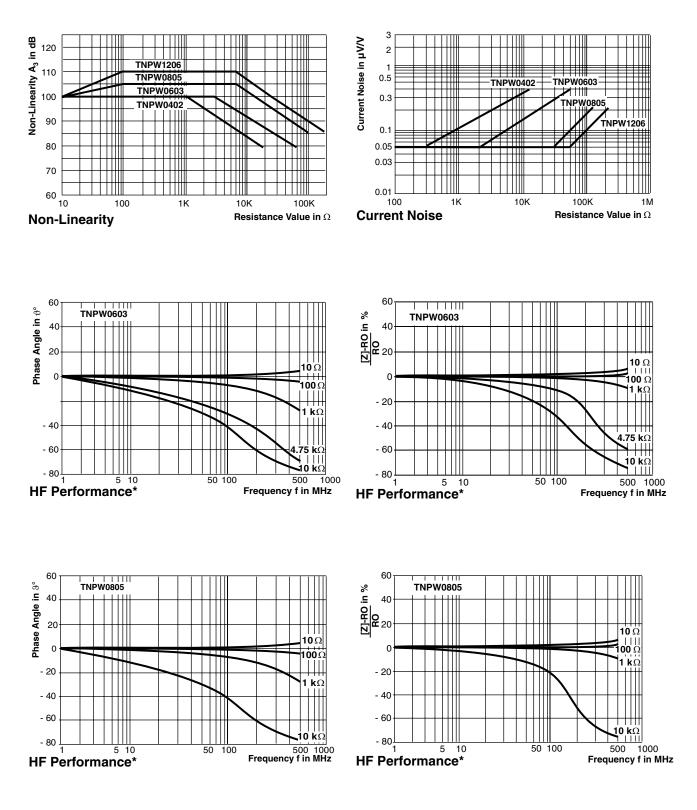


### **TNPW e3**

High Stability Thin Film Flat Chip Resistor  $\leq 0.05$  % (1000 h rated power at 70 °C)

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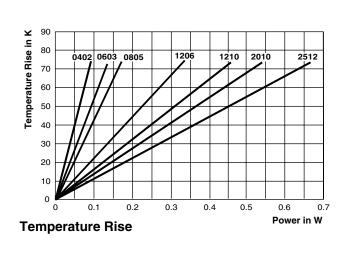
#### FUNCTIONAL PERFORMANCE

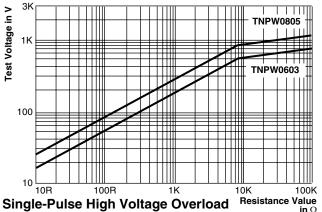


\* Typical figures. HF-characteristic also depends on termination and circuit design.

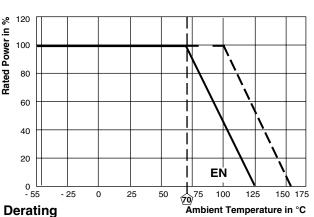
High Stability Thin Film Flat Chip Resistor  $\leq 0.05$  % (1000 h rated power at 70 °C)

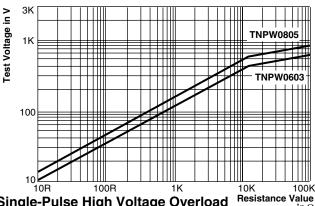




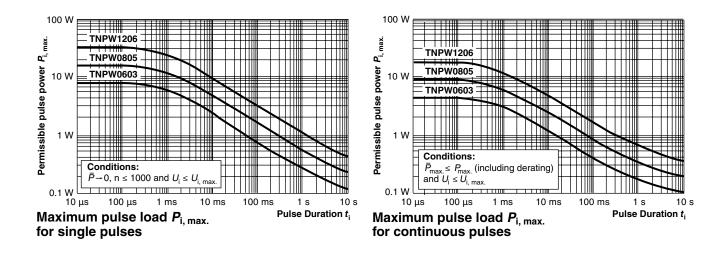






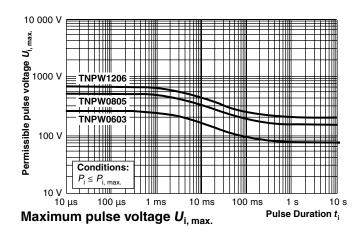








## High Stability Thin Film Flat Chip Resistor $\leq 0.05 \%$ (1000 h rated power at 70 °C)



#### **TEST AND REQUIREMENTS**

All tests are carried out in accordance with the following specifications:

EN 60115-1, Generic specification (includes tests)

EN 140400, Sectional specification (includes schedule for qualification approval)

EN 140401-801, Detail specification (includes schedule for conformance inspection)

The following table contains only the most important tests. For the full test schedule refer to the documents listed above. The testing also covers most of the requirements specified by EIA/IS-703 and JIS-C-5202. The tests are carried out in accordance with IEC 60068 and under standard atmospheric conditions in accordance with IEC 60068-1, 5.3. Climatic category LCT/UCT/56 (rated temperature range: Lower

Category Temperature, Upper Category Temperature; damp heat, long term, 56 days) is valid. Unless otherwise specified the following values apply:

Temperature: 15  $^\circ\text{C}$  to 35  $^\circ\text{C}$  Relative humidity: 45 % to 75 %

Air pressure: 86 kPa to 106 kPa (860 mbar to 1060 mbar).

The components are mounted for testing on boards in accordance with EN 60115-1, 4.31 unless otherwise specified. The parameters stated in the Test Procedures and Requirements table are based on the required tests and permitted limits of EN 140401-801. However, some additional tests and a number of improvements against those minimum requirements have been included.

TEST PR	TEST PROCEDURES AND REQUIREMENTS							
EN 60115-1 CLAUSE	IEC 60068-2 TEST METHOD	TEST	PROCEDURE	REQUIREMENTS PERMISSIBLE CHANGE				
			Stability for product types:					
			TNPW0402					
			TNPW0603					
			TNPW0805					
			TNPW1206					
			TNPW1210					
			TNPW2010					
			TNPW2512					
4.5	-	Resistance		± 1 %; ± 0.5 %; ± 0.1 %				
4.8.4.2	-	Temperature coefficient	At 20/- 55/20 °C ± and 20/125/20 °C	± 50 ppm/K; ± 25 ppm/K; ± 15 ppm/K; ± 10 ppm/K				
		Endurance at	$U = \sqrt{P_{70} \times R}$ or $U = U_{max}$ ; whichever is the less severe;					
4.25.1	25.1 -	- 70 °C	1.5 h on; 0.5 h off;					
			70 °C; 1000 h	± (0.05 % <i>R</i> + 0.01 Ω)				
			70 °C; 8000 h	± (0.1 % <i>R</i> + 0.02 Ω)				

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# High Stability Thin Film Flat Chip Resistor $\leq$ 0.05 % (1000 h rated power at 70 °C)

TEST PR	OCEDURES	AND REQU	REMENTS	
EN 60115-1 CLAUSE	IEC 60068-2 TEST METHOD	TEST	PROCEDURE	REQUIREMENTS PERMISSIBLE CHANGE
			Stability for product types:	
			TNPW0402	
			TNPW0603	
			TNPW0805	
			TNPW1206	
			TNPW1210	
			TNPW2010	
		Endurance et	TNPW2512	
4.25.3	-	Endurance at upper category temperature	125 °C; 1000 h 155 °C; 1000 h	$\pm (0.05 \% R + 0.01 \Omega)$ $\pm (0.1 \% R + 0.02 \Omega)$
4.24	78 (Cab)	Damp heat, steady state	(40 ± 2) °C; 56 days; (93 ± 3) % RH	± (0.1 % <i>R</i> + 0.01 Ω)
4.23		Climatic sequence:		
4.23.2	2 (Ba)	Dry heat	UCT; 16 h	
4.23.3	30 (Db)	Damp	55 °C; 24 h; > 90 % RH; 1 cycle	
4.23.4	1 (Aa)	Cold	LCT; 2 h	± (0.1 % <i>R</i> + 0.02 Ω)
4.23.5	13 (M)	Low air	8.5 kPa; 2 h; 25 ± 10 °C	
4.23.6	30 (Db)	Damp heat, cyclic	55 °C; 5 days; > 95 to 100 % RH; 5 cycles	
4.23.7	-	D.C. load	$U = \sqrt{P_{70} \times R} \le U_{max}; 1 \text{ min}$ LCT = - 55 °C UCT = 125 °C	
-	1 (Aa)	Cold	- 55 °C; 2 h	± (0.05 % <i>R</i> + 0.01 Ω)
4.19	14 (Na)	Rapid change of temperature	30 min at LCT and 30 min at UCT; LCT = - 55 °C; UCT = 125 °C; 1000 cycles	± (0.1 % <i>R</i> + 0.01 Ω)
4.13	-	Short time overload	$U = 2.5 \times \sqrt{P_{70} \times R}$ or $U = 2 \times U_{max}$ ; whichever is the less severe; 5 s	± (0.05 % <i>R</i> + 0.01 Ω)
4.27	-	Single pulse high voltage overload	Severity no. 4: $U = 10 \times \sqrt{P_{70} \times R}$ or $U = 2 \times U_{max}$ ; whichever is the less severe; 10 pulses 10 µs/700 µs	± (0.5 % <i>R</i> + 0.05 Ω) no visible damage
4.37	-	Periodic electric overload	$U = \sqrt{15 \text{ x } P_{70} \text{ x } R} \text{ or}$ $U = 2 \text{ x } U_{\text{max}};$ whichever is the less severe; 0.1 s on; 2.5 s off; 1000 cycles	± (0.5 % <i>R</i> + 0.05 Ω) no visible damage
4.22	6 (Fc)	Vibration	Endurance by sweeping; 10 to 2000 Hz; no resonance; amplitude $\leq$ 1.5 mm or $\leq$ 200 m/s <sup>2</sup> ; 6 h	± (0.05 % <i>R</i> + 0.01 Ω) no visible damage



#### High Stability Thin Film Flat Chip Resistor $\leq$ 0.05 % (1000 h rated power at 70 °C)

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TEST PR	OCEDURES	AND REQUI	REMENTS			
EN 60115-1 CLAUSE	IEC 60068-2 TEST METHOD	TEST	PROCEDURE	REQUIREMENTS PERMISSIBLE CHANGE		
			Stability for product types:			
			TNPW0402			
			TNPW0603			
			TNPW0805			
			TNPW1206			
			TNPW1210			
			TNPW2010			
			TNPW2512			
				Solder bath method; SnPb40; non-activated flux $(215 \pm 3)$ °C; $(3 \pm 0.3)$ s	Good tinning (≥ 95 % covered);	
4.17.2 58 (Td)	Solderability	Solder bath method; SnAg3Cu0.5 or SnAg3.5; non-activated flux (235 ± 3) °C; (2 ± 0.2) s	no visible damage			
4.18.2	58 (Td)	Resistance to soldering heat	Solder bath method; (260 $\pm$ 5) °C; (10 $\pm$ 1) s	± (0.02 % <i>R</i> + 0.01 Ω)		
4.29	45 (XA)	Component solvent resistance	lsopropyl alcohol + 50 °C; method 2	No visible damage		
4.32	01 (11- )		21 (Ue <sub>3</sub> ) She	Shear	RR 1005M and RR 1608M; 9 N	No visible damage
4.02	21 (003)	(adhesion)	RR 2012M and RR 3216M: 45 N	No visible damage		
4.33	21 (Ue <sub>1</sub> )	Substrate bending	Depth 2 mm, 3 times	$\pm$ (0.05 % $R$ + 0.01 $\Omega$ ) no visible damage, no open circuit in bent position		
4.7	-	Voltage proof	$U_{\rm rms} = U_{\rm ins}$ ; 60 ± 5 s	No flashover or breakdown		
4.35	-	Flammability	IEC 60695-11-5, needle flame test; 10 s	No burning after 30 s		
-	-	Damp heat	(85 ± 5) °C; 56 days (85 ± 5) % RH	± (0.25 <i>R</i> + 0.05 Ω)		

#### **APPLICABLE SPECIFICATIONS**

• CECC40000/40400

- EN140400
- EN 140401-801
- EN 60115-1
- IEC 60286-3



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